NSN 5962-01-221-8008

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View Online at https://aerobasegroup.com/nsn/5962-01-221-8008

| 0.840 inches | |
|--|-----------------------|
| | |
| Body Width: | |
| Between 0.220 inches and 0.310 inches | |
| Body Height: | |
| 0.185 inches | |
| Maximum Power Dissipation Rating: | |
| 739.0 milliwatts | |
| Operating Tempurature Range: | |
| -55.0/+125.0 degrees celsius | |
| Storage Tempurature Range: | |
| -65.0/+150.0 degrees celsius | |
| Features Provided: | |
| Hermetically sealed and burn in and bipolar and schottky and programmable and w/active pull-up | |
| Inclosure Material: | |
| Ceramic | |
| Inclosure Configuration: | |
| Dual-in-line | |
| Output Logic Form: | |
| Transistor-transistor logic | |
| Input Circuit Pattern: | |
| 10 input | |
| Case Outline Source And Designator: | |
| D-2 mil-m-38510 | |
| Terminal Surface Treatment: | |
| Gold | |
| Voltage Rating And Type Per Characteristic: | |
| 7.0 volts power source | |
| Time Rating Per Chacteristic: | |
| 75.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay tir | ne, high to low level |
| output | |
| Memory Device Type: | |
| Rom | |
| Precious Material And Location: | |
| Terminal surface option gold | |
| Precious Material: | |
| Gold | |
| Test Data Document: | |
| 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). | |
| Terminal Type And Quantity: | |
| 16 printed circuit | |
| Shelf Life: | |
| N/a | |

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

